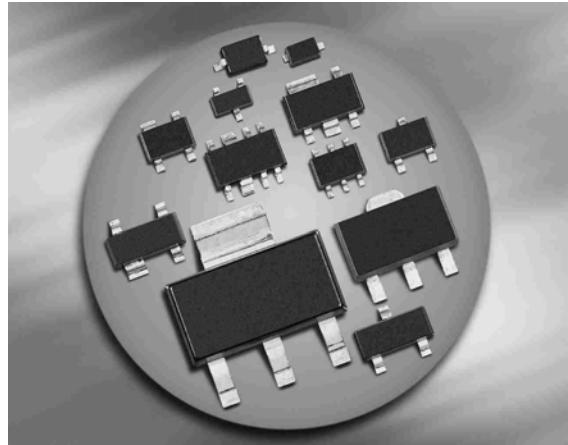


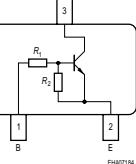
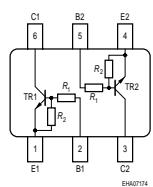
NPN Silicon Digital Transistor

- Switching circuit, inverter, interface circuit, driver circuit
- Built in bias resistor ($R_1=2.2\text{k}\Omega$, $R_2=2.2\text{k}\Omega$)
- For 6-PIN packages: two (galvanic) internal isolated transistors with good matching in one package

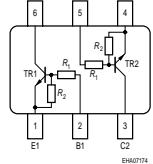
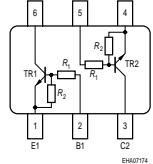


BCR103/F

BCR103L3/T



BCR103U



| Type | Marking | Pin Configuration | | | | | | Package |
|----------|---------|-------------------|------|------|------|------|------|----------|
| BCR103 | WAs | 1=B | 2=E | 3=C | - | - | - | SOT23 |
| BCR103F | WAs | 1=B | 2=E | 3=C | - | - | - | TSFP-3 |
| BCR103L3 | WA | 1=B | 2=E | 3=C | - | - | - | TSLP-3-4 |
| BCR103T | WAs | 1=B | 2=E | 3=C | - | - | - | SC75 |
| BCR103U | WAs | 1=E1 | 2=B1 | 3=C2 | 4=E2 | 5=B2 | 6=C1 | SC74 |

Maximum Ratings

| Parameter | Symbol | Value | Unit |
|--|-------------|-------------|------------------|
| Collector-emitter voltage | V_{CEO} | 50 | V |
| Collector-base voltage | V_{CBO} | 50 | |
| Emitter-base voltage | V_{EBO} | 5 | |
| Input on voltage | $V_{i(on)}$ | 10 | |
| Collector current | I_C | 100 | mA |
| Total power dissipation- BCR103, $T_S \leq 102^\circ\text{C}$ | P_{tot} | 200 | mW |
| BCR103F, $T_S \leq 128^\circ\text{C}$ | | 250 | |
| BCR103L3, $T_S \leq 135^\circ\text{C}$ | | 250 | |
| BCR103T, $T_S \leq 109^\circ\text{C}$ | | 250 | |
| BCR103U, $T_S \leq 118^\circ\text{C}$ | | 250 | |
| Junction temperature | T_j | 150 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -65 ... 150 | |

Thermal Resistance

| Parameter | Symbol | Value | Unit |
|--|------------|------------|------|
| Junction - soldering point ¹⁾ BCR103 | R_{thJS} | ≤ 240 | K/W |
| BCR103F | | ≤ 90 | |
| BCR103L3 | | ≤ 60 | |
| BCR103T | | ≤ 165 | |
| BCR103U | | ≤ 133 | |

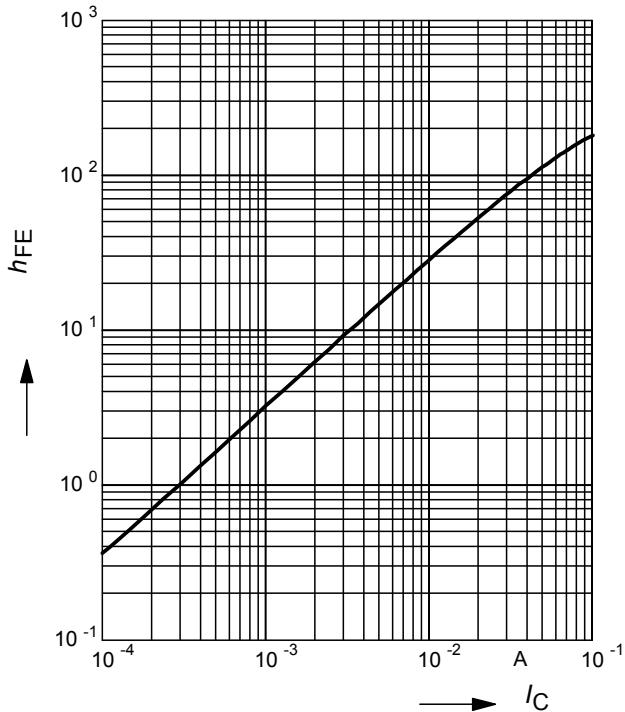
¹For calculation of R_{thJA} please refer to Application Note Thermal Resistance

Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

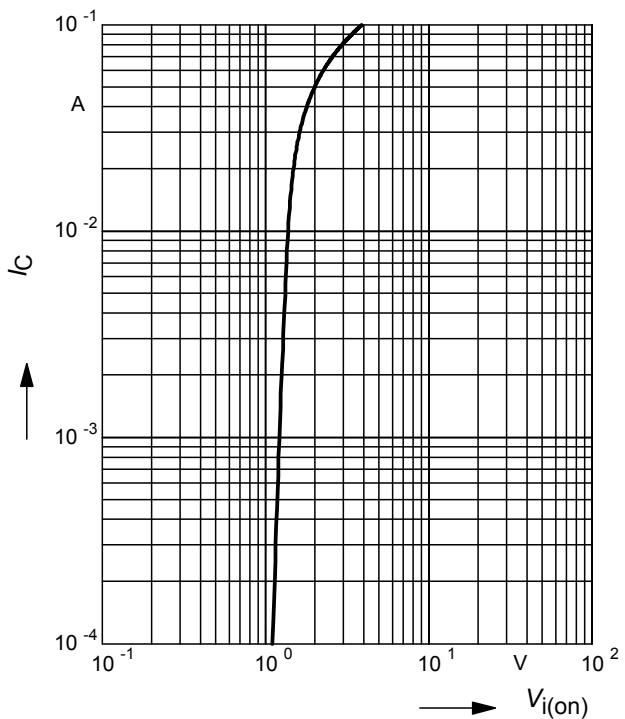
| Parameter | Symbol | Values | | | Unit |
|---|-----------------------------|--------|------|------|------|
| | | min. | typ. | max. | |
| DC Characteristics | | | | | |
| Collector-emitter breakdown voltage $I_C = 100 \mu\text{A}, I_B = 0$ | $V_{(\text{BR})\text{CEO}}$ | 50 | - | - | V |
| Collector-base breakdown voltage $I_C = 10 \mu\text{A}, I_E = 0$ | $V_{(\text{BR})\text{CBO}}$ | 50 | - | - | |
| Collector-base cutoff current $V_{CB} = 40 \text{ V}, I_E = 0$ | I_{CBO} | - | - | 100 | nA |
| Emitter-base cutoff current $V_{EB} = 10 \text{ V}, I_C = 0$ | I_{EBO} | - | - | 3.5 | mA |
| DC current gain ¹⁾ $I_C = 20 \text{ mA}, V_{CE} = 5 \text{ V}$ | h_{FE} | 20 | - | - | - |
| Collector-emitter saturation voltage ¹⁾ $I_C = 20 \text{ mA}, I_B = 1 \text{ mA}$ | V_{CEsat} | - | - | 0.3 | V |
| Input off voltage $I_C = 100 \mu\text{A}, V_{CE} = 5 \text{ V}$ | $V_{i(\text{off})}$ | 0.8 | - | 1.5 | |
| Input on voltage $I_C = 2 \text{ mA}, V_{CE} = 0.3 \text{ V}$ | $V_{i(\text{on})}$ | 0.8 | - | 2.5 | |
| Input resistor | R_1 | 1.5 | 2.2 | 2.9 | kΩ |
| Resistor ratio | R_1/R_2 | 0.9 | 1 | 1.1 | - |
| AC Characteristics | | | | | |
| Transition frequency $I_C = 10 \text{ mA}, V_{CE} = 5 \text{ V}, f = 1 \text{ MHz}$ | f_T | - | 140 | - | MHz |
| Collector-base capacitance $V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}$ | C_{cb} | - | 3 | - | pF |

¹Pulse test: $t < 300\mu\text{s}$; $D < 2\%$

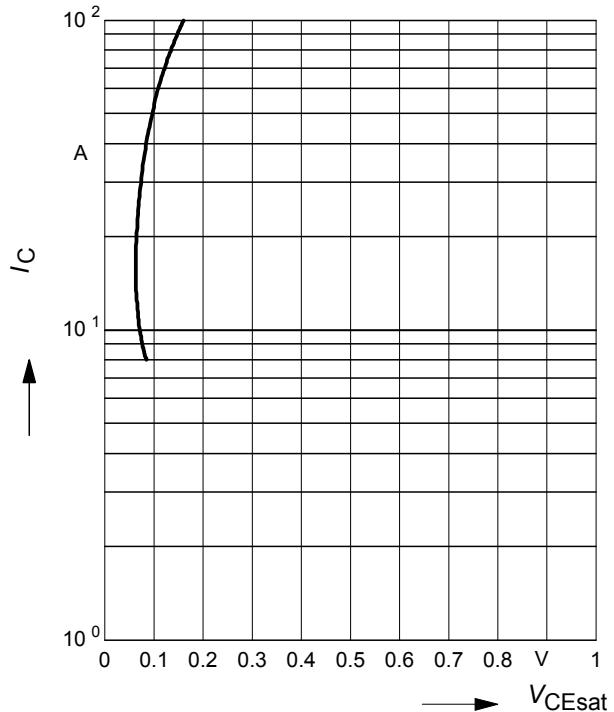
DC current gain $h_{FE} = f(I_C)$
 $V_{CE} = 5V$ (common emitter configuration)



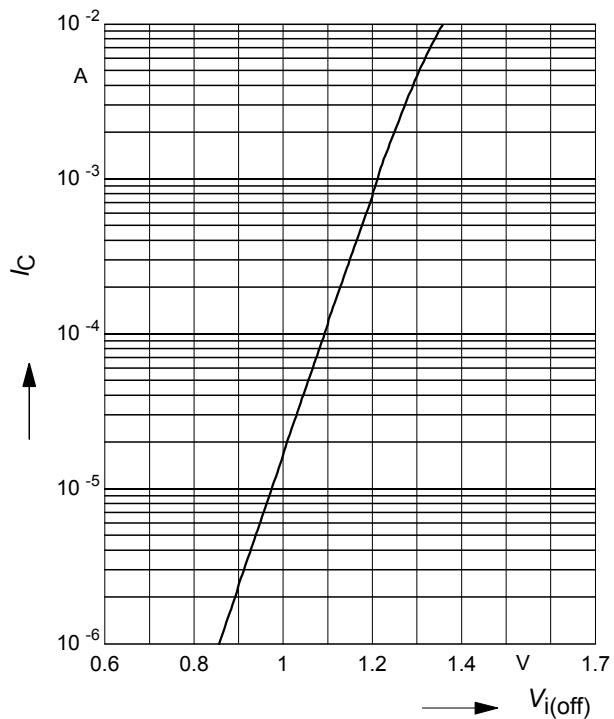
Input on Voltage $V_{i(on)} = f(I_C)$
 $V_{CE} = 0.3V$ (common emitter configuration)



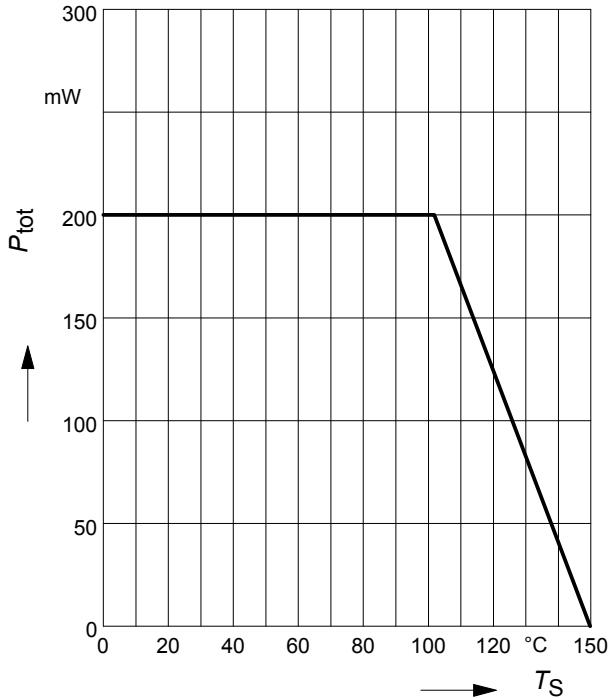
Collector-emitter saturation voltage
 $V_{CEsat} = f(I_C), h_{FE} = 20$



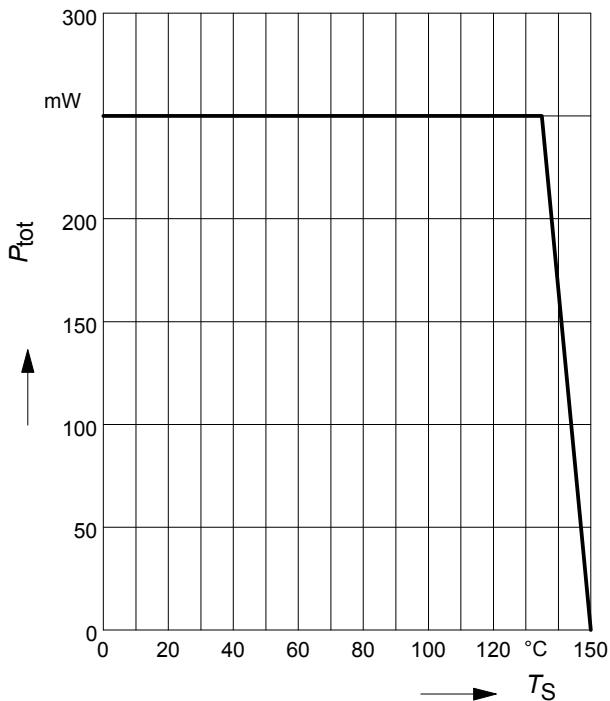
Input off voltage $V_{i(off)} = f(I_C)$
 $V_{CE} = 5V$ (common emitter configuration)



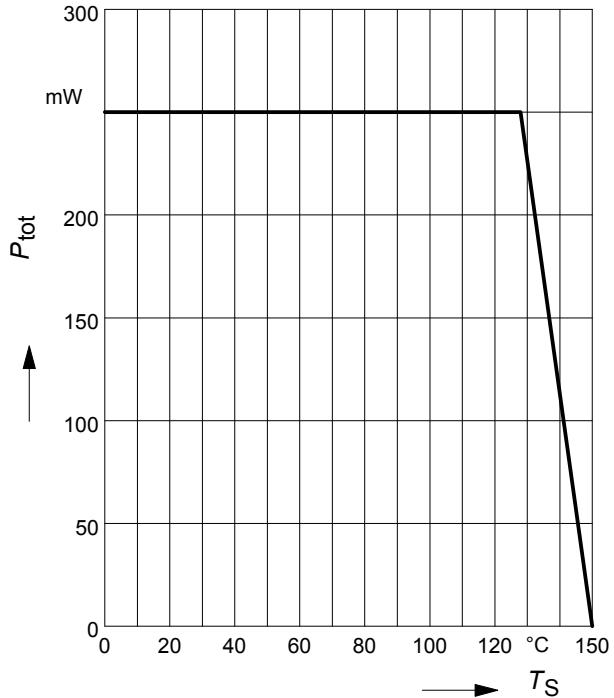
Total power dissipation $P_{\text{tot}} = f(T_S)$
BCR103



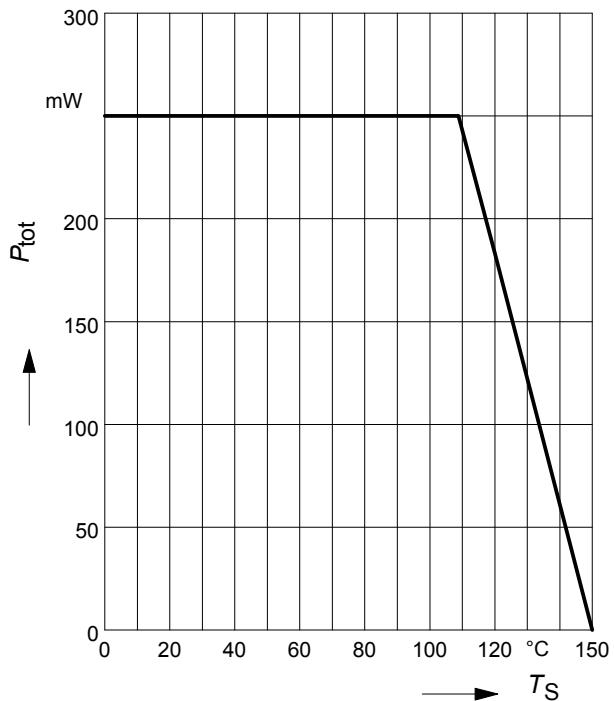
Total power dissipation $P_{\text{tot}} = f(T_S)$
BCR103L3



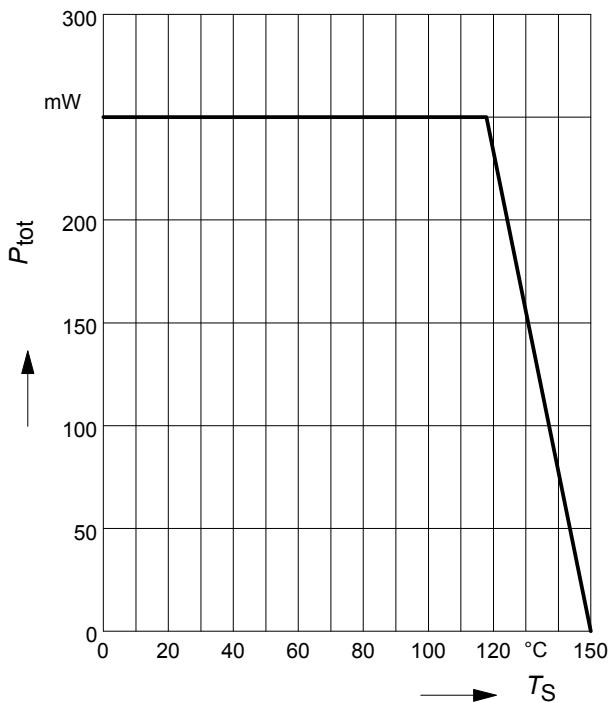
Total power dissipation $P_{\text{tot}} = f(T_S)$
BCR103F



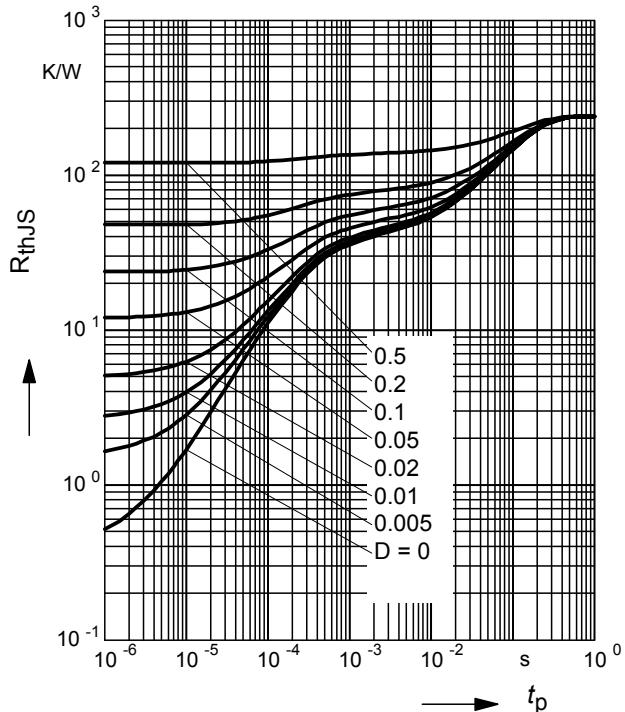
Total power dissipation $P_{\text{tot}} = f(T_S)$
BCR103T



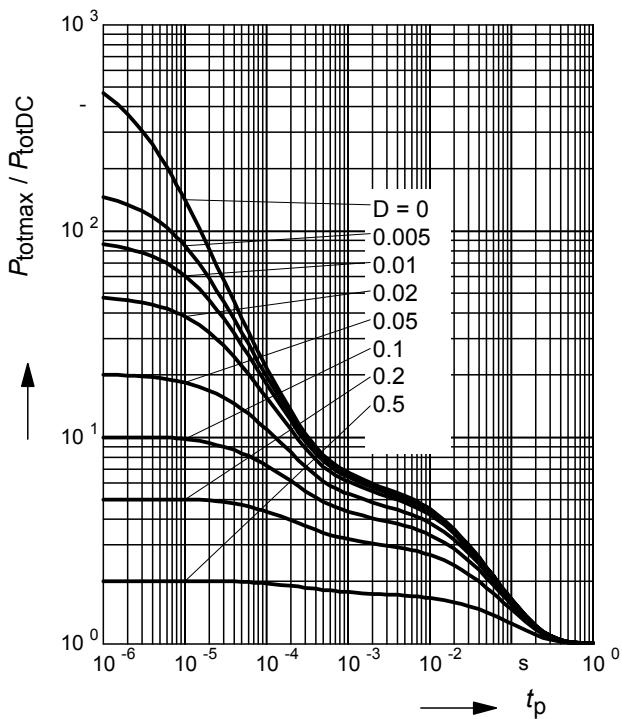
Total power dissipation $P_{\text{tot}} = f(T_S)$
BCR103U



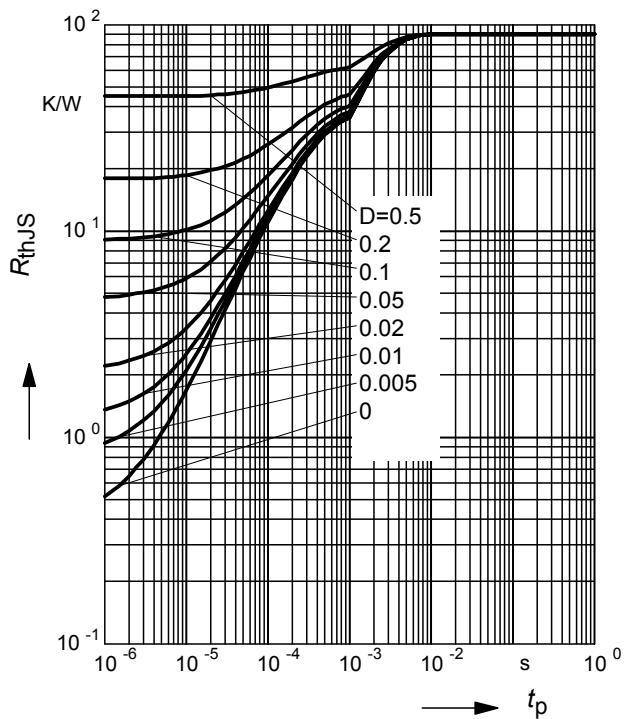
Permissible Pulse Load $R_{\text{thJS}} = f(t_p)$
BCR103



Permissible Pulse Load
 $P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$
BCR103



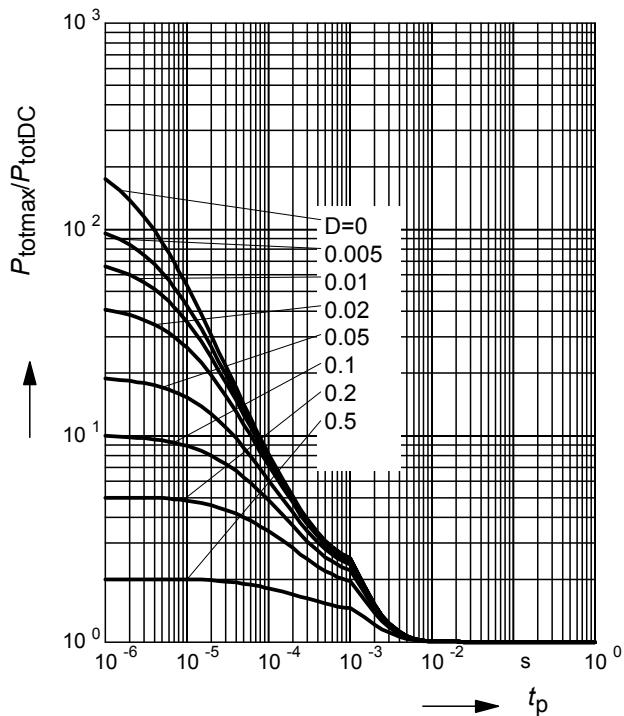
Permissible Pulse Load $R_{\text{thJS}} = f(t_p)$
BCR103F



Permissible Pulse Load

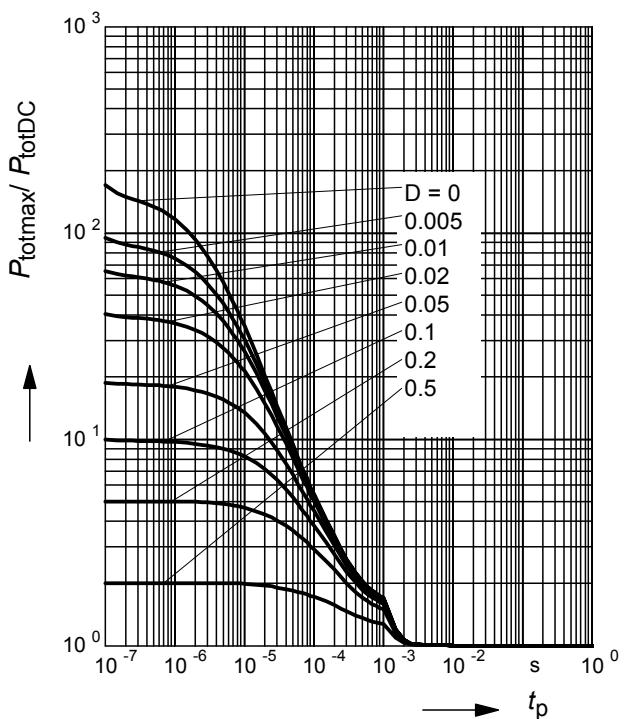
$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR103F

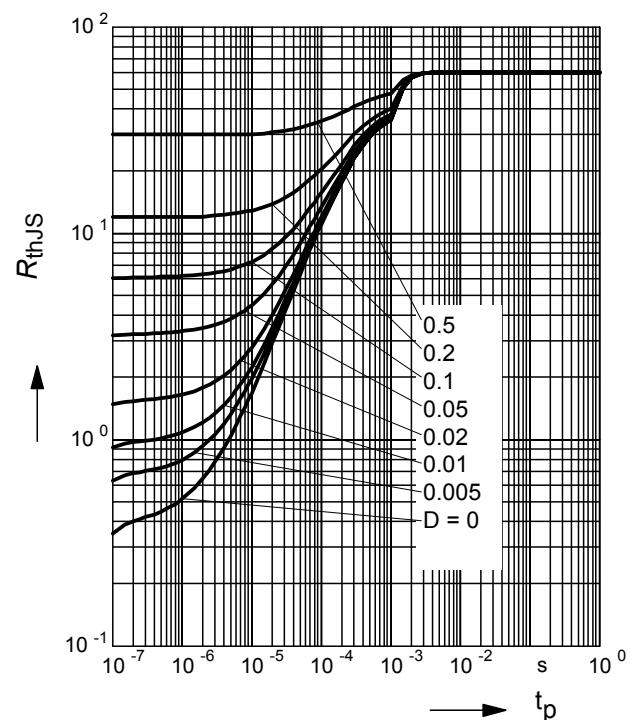

Permissible Pulse Load

$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

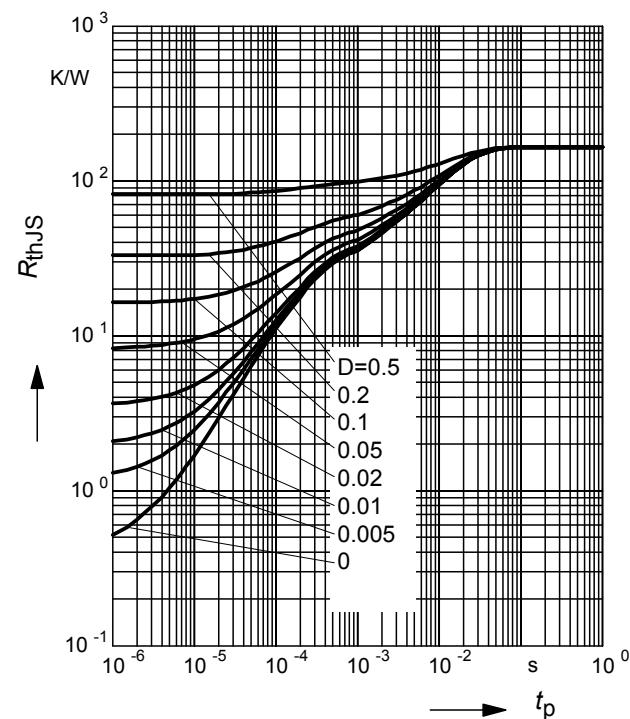
BCR103L3


Permissible Puls Load $R_{\text{thJS}} = f(t_p)$

BCR103L3


Permissible Puls Load $R_{\text{thJS}} = f(t_p)$

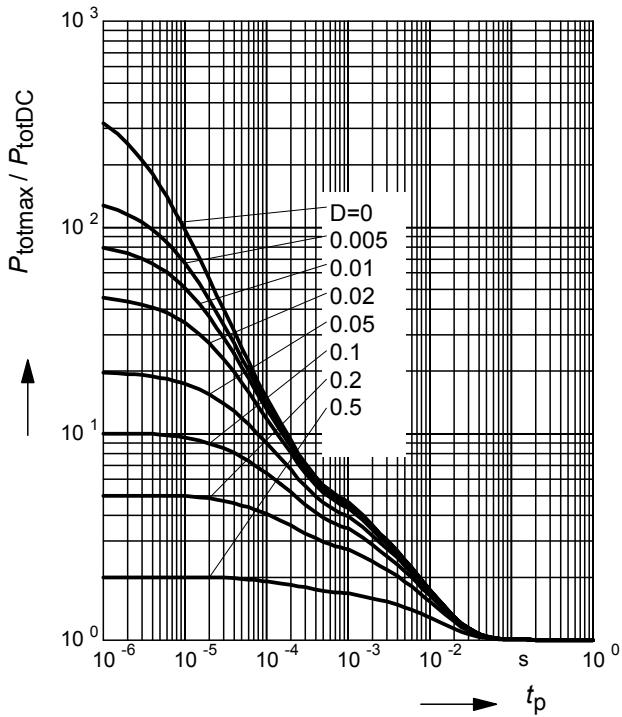
BCR103T



Permissible Pulse Load

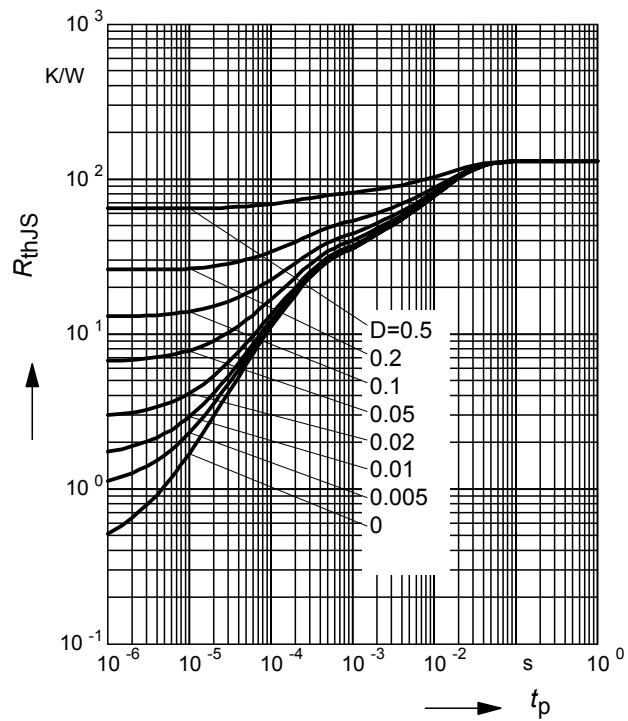
$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR103T



Permissible Pulse Load $R_{\text{thJS}} = f(t_p)$

BCR103U



Permissible Pulse Load

$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR103U

